



20 V, N-channel Trench MOSFET 16 February 2021

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Extended temperature range T_i = 175 °C ٠
- Trench MOSFET technology
- Very fast switching
- ElectroStatic Discharge (ESD) protection > 2 kV HBM (class H2)
- AEC-Q101 gualified

3. Applications

- DC to DC conversion
- High-speed line driver •
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	-	7.3	А
Static characte	eristics		•				
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 7.3 A; T _j = 25 °C		-	13	17	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2. F	inning infor	nation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain		G S 017aaa255

6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
PMV13XNEA		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PMV13XNEA	XQ%

[1] % = placeholder for manufacturing site code

20 V, N-channel Trench MOSFET

8. Limiting values

Table 5. Limiting values

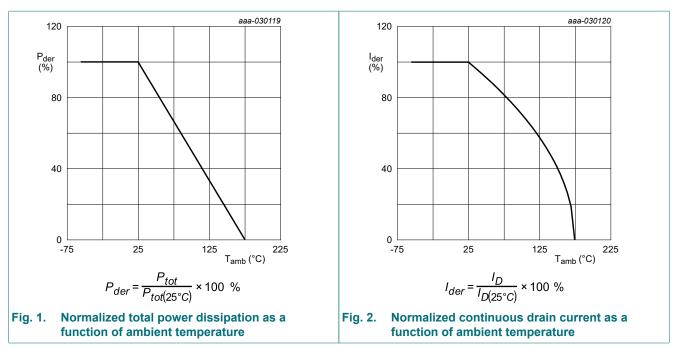
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	7.3	А
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	4.6	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	30	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	610	mW
			[1]	-	1.4	W
		T _{sp} = 25 °C		-	8.3	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drai	n diode			I		
I _S	source current	T _{amb} = 25 °C	[1]	-	1.4	А
ESD maxim	um rating					_
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	T _{j(init)} = 25 °C; I _D = 1.3 A; DUT in v avalanche (unclamped)		-	13	mJ
		1	I	I	1	

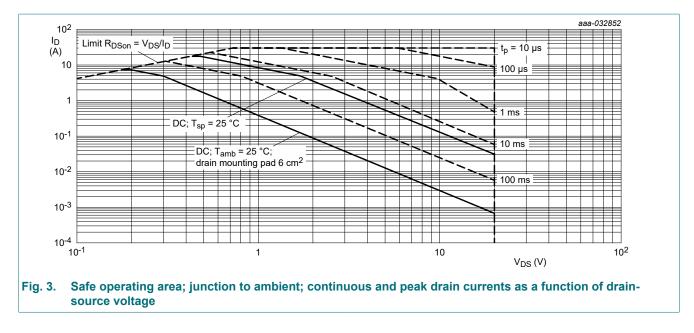
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.



20 V, N-channel Trench MOSFET

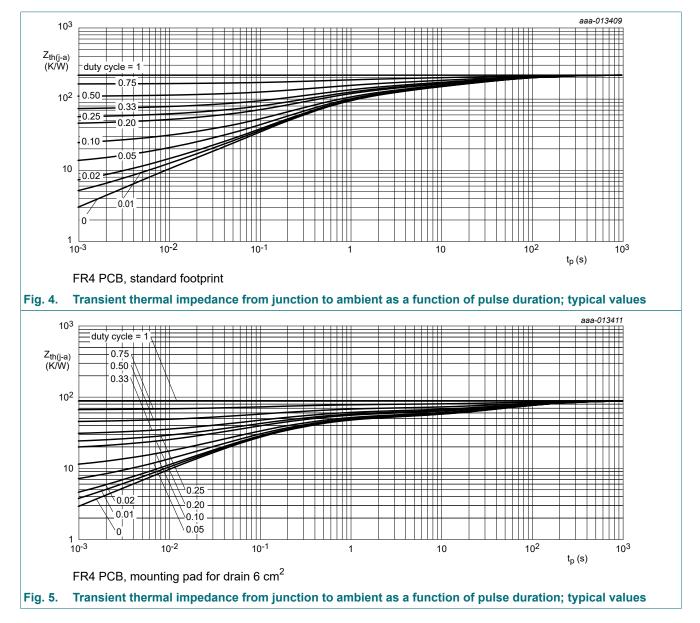


9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient	thermal resistance from	i în free air [[1]	-	208	245	K/W
		[2]	-	88	104	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	13	18	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

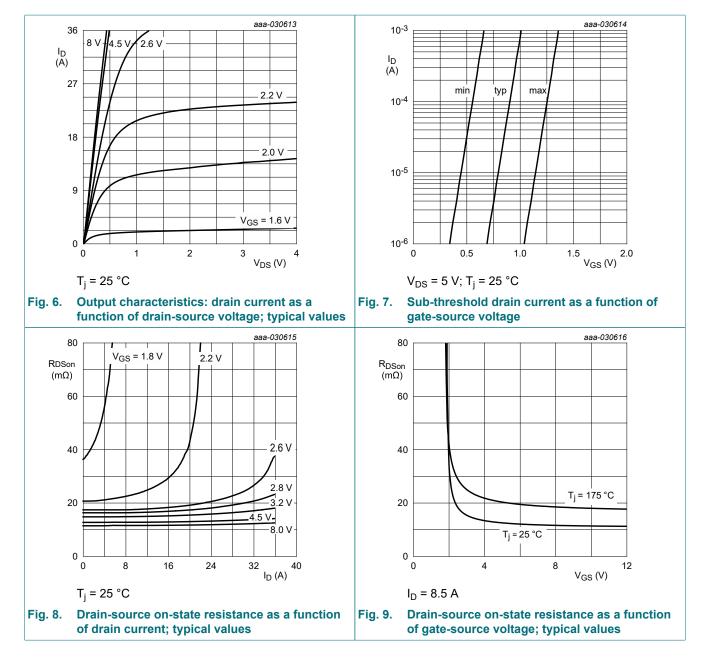
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



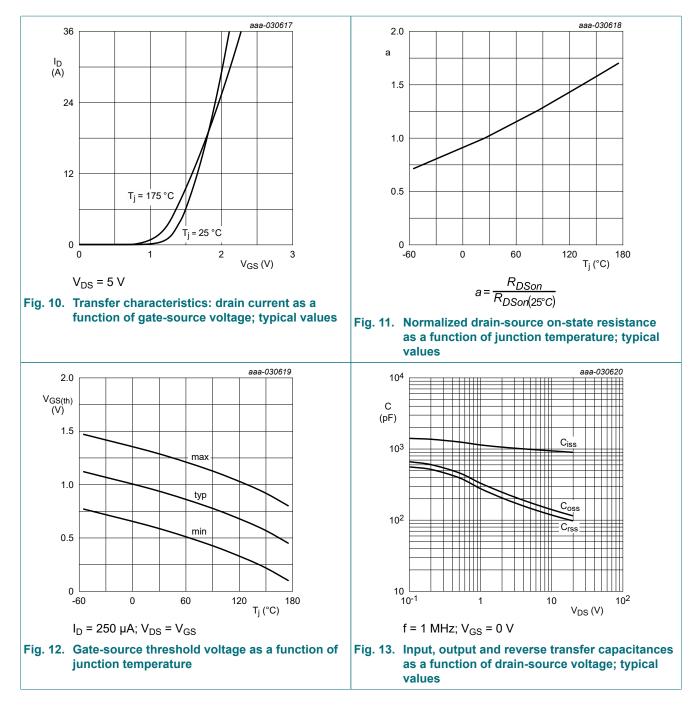
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	20	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	0.6	0.95	1.3	V
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	2	μA
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μA
R _{DSon}	drain-source on-state resistance	V _{GS} = 8 V; I _D = 7.3 A; T _j = 25 °C	-	11	15	mΩ
		V _{GS} = 8 V; I _D = 7.3 A; T _j = 175 °C	-	19	26	mΩ
		V _{GS} = 4.5 V; I _D = 7.3 A; T _j = 25 °C	-	13	17	mΩ
		V _{GS} = 2.5 V; I _D = 2 A; T _j = 25 °C	-	17	25	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 8.5 A; T _j = 25 °C	-	14.4	-	S
R _G	gate resistance	f = 1 MHz	-	1.4	-	Ω
Dynamic ch	aracteristics					
Q _{G(tot)}	total gate charge	V _{DS} = 10 V; I _D = 9 A; V _{GS} = 4.5 V;	-	9.8	15	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.5	-	nC
Q _{GD}	gate-drain charge		-	2.9	-	nC
C _{iss}	input capacitance	V _{DS} = 10 V; f = 1 MHz; V _{GS} = 0 V;	-	931	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	144	-	pF
C _{rss}	reverse transfer capacitance		-	121	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 10 V; I _D = 9 A; V _{GS} = 4.5 V;	-	4	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	7	-	ns
t _{d(off)}	turn-off delay time		-	15	-	ns
t _f	fall time		-	9	-	ns
Source-drai	n diode		1			
V _{SD}	source-drain voltage	I _S = 1.4 A; V _{GS} = 0 V; T _j = 25 °C	-	0.7	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 2 \text{ A}; \text{ d}_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-	10	-	ns
Q _r	recovered charge	V _{DS} = 10 V; T _j = 25 °C	-	3	-	nC

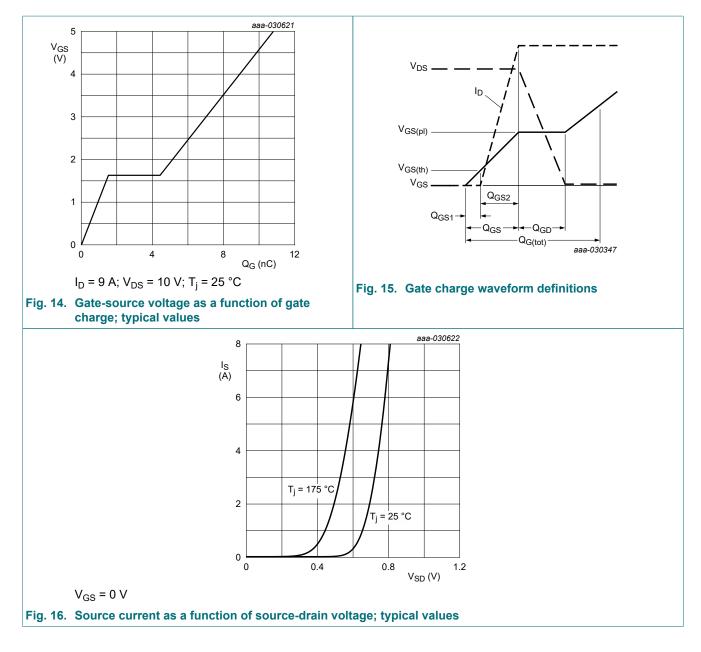
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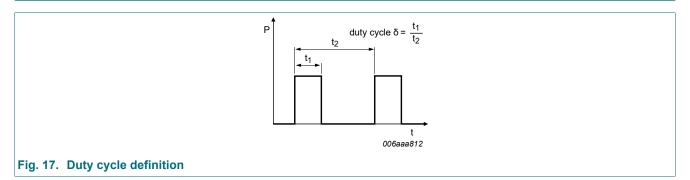
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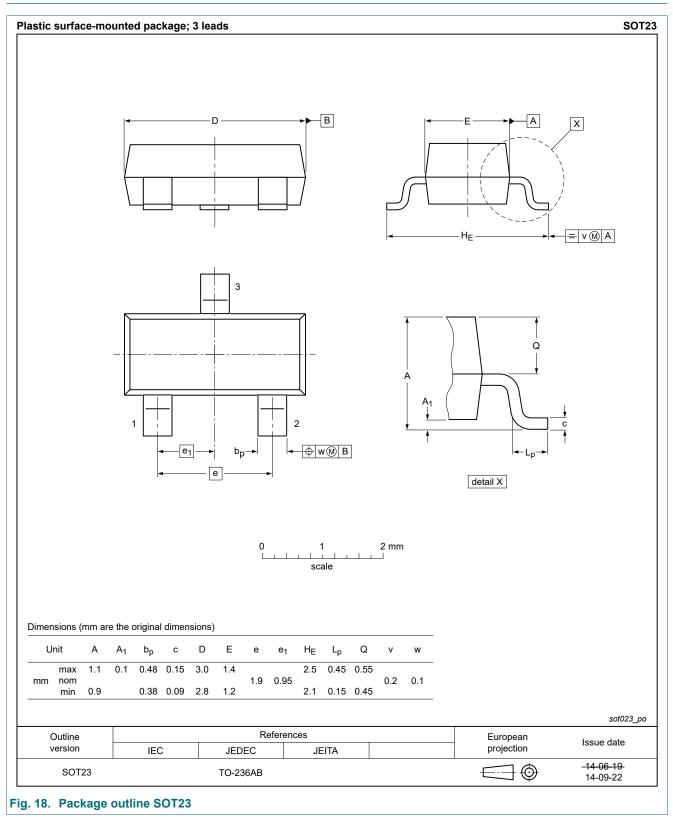
11. Test information



Quality information

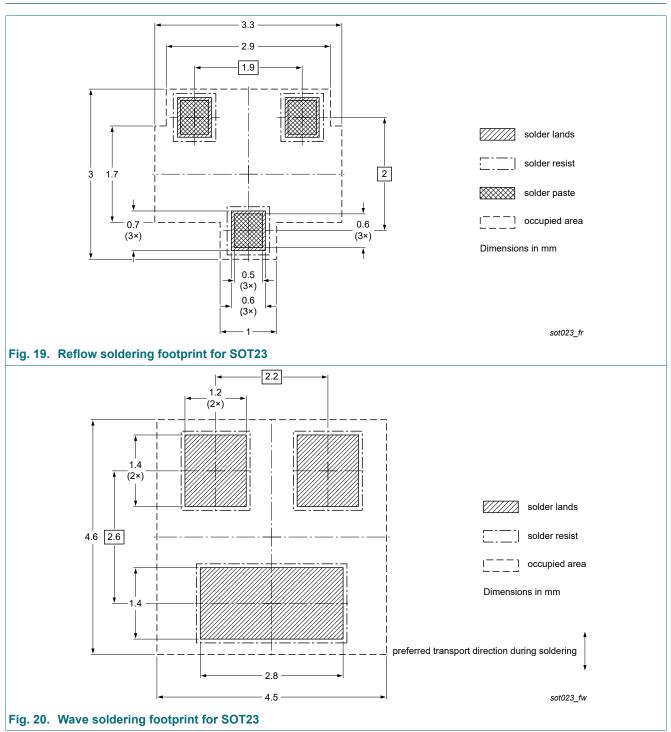
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



20 V, N-channel Trench MOSFET

13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMV13XNEA v.1	20210216	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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20 V, N-channel Trench MOSFET

Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
	Thermal characteristics	
10.	Characteristics	6
11.	Test information	. 10
12.	Package outline	. 11
	Soldering	
14.	Revision history	13
	۔ Legal information	
	-	

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